NSN 5961-01-121-6695

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-121-6695

Inclosure Material:

Metal

Overall Length:

Between 0.345 inches and 0.400 inches

End Application:

Gmsrstestset 81205

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.370 inches and 0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 0.50 amperes source cutoff current and 5.00 amperes source cutoff current

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug and 1 wire hook

Specification Data:

81349-mil-s-19500/374 government specification

Shelf Life:

N/a

Unit Of Measure:

NSN 5961-01-121-6695

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

